

TPS22916xx 1-V–5.5-V, 2-A, 60-mΩ Ultra-Low Leakage Load Switch

1 Features

- Input operating voltage range (V_{IN}): 1 V–5.5 V
- Maximum continuous current (I_{MAX}): 2 A
- ON-resistance (R_{ON}):
 - 5 V_{IN} = 60 mΩ (typ.), 100 mΩ (85°C max.)
 - 1.8 V_{IN} = 100 mΩ (typ.), 150 mΩ (85°C max.)
 - 1 V_{IN} = 200 mΩ (typ.), 325 mΩ (85°C max.)
- Ultra-low power consumption:
 - ON state (I_Q): 0.5 μ A (typ.), 1 μ A (max.)
 - OFF state (I_{SD}): 10 nA (typ.), 100 nA (max.)
 - TPS22916BL/CL/CNL (I_{SD}): 100 nA (typ.), 300 nA (max.)
- Smart ON pin pulldown (R_{PD}):
 - ON $\geq V_{IH}$ (I_{ON}): 10 nA (max.)
 - ON $\leq V_{IL}$ (R_{PD}): 750 kΩ (typ.)
- Slow Timing in C Version Limits Inrush Current:
 - 5-V turn-on time (t_{ON}): 1400 μ s at 5 mV/ μ s
 - 1.8-V turn-on time (t_{ON}): 3000 μ s at 1 mV/ μ s
 - 1-V turn-on time (t_{ON}): 6500 μ s at 0.3 mV/ μ s
- Fast timing in b version reduces wait time:
 - 5-V turn-on time (t_{ON}): 115 μ s at 57 mV/ μ s
 - 1.8-V turn-on time (t_{ON}): 250 μ s at 12 mV/ μ s
 - 1-V turn-on time (t_{ON}): 510 μ s at 3.3 mV/ μ s
- Always-ON true Reverse Current Blocking (RCB):
 - Activation current (I_{RCB}): –500 mA (typ.)
 - Reverse leakage ($I_{IN,RCB}$): –300 nA (max.)
- Quick Output Discharge (QOD): 150 Ω (typ.) (N version has no QOD)
- Active low enable option (L versions)

2 Applications

- Wearables
- Smartphones
- Tablets
- Portable speakers

3 Description

The TPS22916xx is a small, single channel load switch using a low leakage P-Channel MOSFET for minimum power loss. Advanced gate control design supports operating voltages as low as 1 V with minimal increase in ON-resistance and power loss.

Multiple timing options are available to support various system loading conditions. For heavy capacitive loads, the slow turn-on timing in the C version minimizes the inrush current. In cases with light capacitive loads, the fast timing in the B version reduces required wait time.

The switch ON state is controlled by a digital input that is capable of interfacing directly with low-voltage control signals. Both Active High and Active Low (L) versions are available. When power is first applied, a smart pulldown is used to keep the ON pin from floating until system sequencing is complete. After the ON pin is deliberately driven high ($\geq V_{IH}$), the smart pulldown is disconnected to prevent unnecessary power loss.

The TPS22916xx is available in a small, space saving 0.78 mm \times 0.78 mm, 0.4-mm pitch, 0.5-mm height 4-pin Wafer-Chip-Scale (WCSP) package (YFP). The device is characterized for operation over a temperature range of –40°C to +85°C.

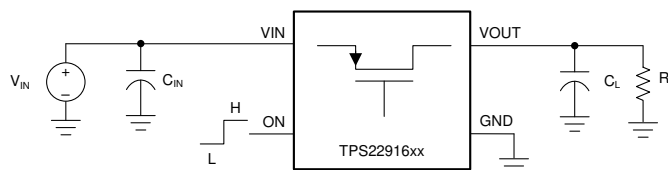
Device Information⁽¹⁾

PART NUMBER	PACKAGE	BODY SIZE (NOM)
TPS22916xx	WCSP (4)	0.78 mm \times 0.78 mm

- (1) For all available packages, see the orderable addendum at the end of the data sheet.

Device Comparison Table

VERSION	TIMING	QOD	ENABLE (ON)
TPS22916B	Fast	Yes	Active High
TPS22916BL	Fast	Yes	Active Low
TPS22916C	Slow	Yes	Active High
TPS22916CN	Slow	No	Active High
TPS22916CL	Slow	Yes	Active Low
TPS22916CNL	Slow	No	Active Low



Copyright © 2017, Texas Instruments Incorporated

Simplified Schematic

Table of Contents

1 Features	1	9 Application and Implementation	18
2 Applications	1	9.1 Application Information.....	18
3 Description	1	9.2 Typical Application.....	18
4 Revision History	2	10 Power Supply Recommendations	19
5 Pin Configuration and Functions	3	11 Layout	20
6 Specifications	4	11.1 Layout Guidelines.....	20
6.1 Absolute Maximum Ratings.....	4	11.2 Layout Example.....	20
6.2 ESD Ratings.....	4	11.3 Thermal Considerations.....	20
6.3 Recommended Operating Conditions.....	4	12 Device and Documentation Support	21
6.4 Thermal Information.....	4	12.1 Documentation Support.....	21
6.5 Electrical Characteristics.....	5	12.2 Receiving Notification of Documentation Updates.....	21
6.6 Switching Characteristics.....	6	12.3 Support Resources.....	21
6.7 Typical Characteristics.....	8	12.4 Trademarks.....	21
7 Parameter Measurement Information	15	12.5 Electrostatic Discharge Caution.....	21
8 Detailed Description	16	12.6 Glossary.....	21
8.1 Overview.....	16	13 Mechanical, Packaging, and Orderable Information	21
8.2 Functional Block Diagram.....	16	13.1 Tape and Reel Information.....	22
8.3 Feature Description.....	16		
8.4 Device Functional Modes.....	17		

4 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Revision E (September 2020) to Revision F (December 2021)	Page
• Added TPS22916CNL and TPS22916BL orderables to the data sheet.....	1
Changes from Revision D (October 2019) to Revision E (September 2020)	Page
• Updated the numbering format for tables, figures and cross-references throughout the document.....	1
Changes from Revision C (October 2018) to Revision D (October 2019)	Page
• Changed package dimensions from 0.74 mm x 0.74 mm to 0.78 mm x 0.78 mm.....	1
Changes from Revision B (December 2017) to Revision C (October 2018)	Page
• Changed Package Drawing Dimensions	21
Changes from Revision A (September 2017) to Revision B (December 2017)	Page
• Changed Pinout drawing labeled Laser Marking.....	1
Changes from Revision * (July 2017) to Revision A (September 2017)	Page
• Changed device document from Advanced Info to Production Data	1

5 Pin Configuration and Functions

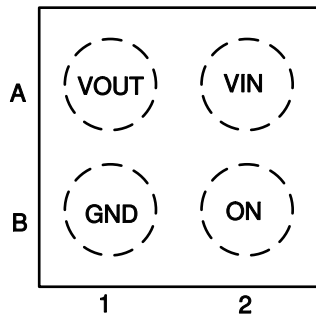


Figure 5-1. YFP Package 4-Pin WSON Laser Marking View

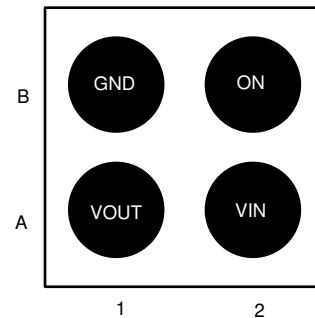


Figure 5-2. YFP Package 4-Pin WSON Bump View

Table 5-1. Pin Functions

PIN		TYPE	DESCRIPTION
NO.	NAME		
A1	VOUT	Power	Switch output
A2	VIN	Power	Switch input
B1	GND	Ground	Device ground
B2	ON	Digital input	Device enable

6 Specifications

6.1 Absolute Maximum Ratings

Over operating free-air temperature range (unless otherwise noted)⁽¹⁾

		MIN	MAX	UNIT
V _{IN}	Input voltage	-0.3	6	V
V _{OUT}	Output voltage	-0.3	6	V
V _{ON}	Enable voltage	-0.3	6	V
I _{MAX}	Maximum continuous switch current		2	A
I _{PLS}	Maximum pulsed switch current, pulse < 300- μ s, 2% duty cycle		2.5	A
T _{J,MAX}	Maximum junction temperature		125	°C
T _{STG}	Storage temperature	-65	150	°C
T _{LEAD}	Maximum Lead temperature (10-s soldering time)		300	°C

- (1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions*. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

6.2 ESD Ratings

		VALUE	UNIT
V _(ESD)	Electrostatic discharge	Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 ⁽¹⁾	V
		Charged-device model (CDM), per JEDEC specification JESD22-C101 ⁽²⁾	
		±2000	
		±500	

- (1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process. Manufacturing with less than 500-V HBM is possible with the necessary precautions. Pins listed as ±2000 V may actually have higher performance.
- (2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process. Manufacturing with less than 250-V CDM is possible with the necessary precautions. Pins listed as ±500 V may actually have higher performance.

6.3 Recommended Operating Conditions

Over operating free-air temperature range (unless otherwise noted)

		MIN	MAX	UNIT
V _{IN}	Input voltage	1	5.5	V
V _{OUT}	Output voltage	0	5.5	V
V _{IH}	High-level input voltage, ON	1	5.5	V
V _{IL}	Low-level input voltage, ON	0	0.35	V
T _A	Operating free-air temperature	-40	85	°C

6.4 Thermal Information

Thermal Parameters ⁽¹⁾	TPS22916xx	UNIT	
	YFP (WCSP)		
	4 PINS		
θ_{JA}	Junction-to-ambient thermal resistance	193	°C/W
θ_{Jtop}	Junction-to-case (top) thermal resistance	2.3	°C/W
θ_{JB}	Junction-to-board thermal resistance	36	°C/W
ψ_{JT}	Junction-to-top characterization parameter	12	°C/W
ψ_{JB}	Junction-to-board characterization parameter	36	°C/W

- (1) For more information about traditional and new thermal metrics, see the [Semiconductor and IC Package Thermal Metrics](#) application report.

6.5 Electrical Characteristics

Unless otherwise noted, the specification in the following table applies for all variants over the entire recommended power supply voltage range of 1 V to 5.5 V unless noted otherwise. Typical Values are at 25°C.

PARAMETER		TEST CONDITIONS	T _J	MIN	TYP	MAX	UNIT
INPUT SUPPLY (VIN)							
I _{Q,VIN}	V _{IN} Quiescent current	Enabled, V _{OUT} = Open	–40°C to +85°C	0.5	1.0		μA
I _{SD,VIN}	V _{IN} Shutdown current	Disabled, V _{OUT} = GND (TPS22916B/C/CN)	–40°C to +85°C	10	100		nA
		Disabled, V _{OUT} = GND (TPS22916BL/CL/CNL)	–40°C to +85°C	100	300		nA
ON-RESISTANCE (R_{ON})							
R _{ON}	ON-Resistance	I _{OUT} = 200 mA	V _{IN} = 5 V	25°C	60	80	mΩ
				–40°C to +85°C		100	
				–40°C to +105°C		120	
			V _{IN} = 3.6 V	25°C	70	90	
				–40°C to +85°C		120	
				–40°C to +105°C		140	
			V _{IN} = 1.8 V	25°C	100	125	
				–40°C to +85°C		150	
				–40°C to +105°C		175	
			V _{IN} = 1.2 V	25°C	150	200	
				–40°C to +85°C		250	
				–40°C to +105°C		300	
			V _{IN} = 1 V	25°C	200	275	
				–40°C to +85°C		325	
				–40°C to +105°C		375	
ENABLE PIN (ON)							
I _{ON}	ON Pin leakage	Enabled	–40°C to +85°C	–10		10	nA
R _{PD}	Smart Pull Down Resistance	Disabled	–40°C to +85°C	750			kΩ
REVERSE CURRENT BLOCKING (RCB)							
I _{RCB}	RCB Activation Current	Enabled, V _{OUT} > V _{IN}	–40°C to +85°C	–500			mA
t _{RCB}	RCB Activation time	Enabled, V _{OUT} > V _{IN} + 200mV	–40°C to +85°C	10			μs
V _{RCB}	RCB Release Voltage	Enabled, V _{OUT} > V _{IN}	–40°C to +85°C	25			mV
I _{IN,RCB}	V _{IN} Reverse Leakage Current	0 V ≤ V _{IN} + V _{RCB} ≤ V _{OUT} ≤ 5.5 V	–40°C to +85°C	–300			nA
QUICK OUTPUT DISCHARGE (QOD)							
QOD ⁽¹⁾	Output discharge resistance	Disabled (Not in TPS22916CN/CNL)	–40°C to +85°C	150			Ω

(1) For more information on which devices include quick output discharge, see the [Device Functional Modes](#) section.

6.6 Switching Characteristics

Unless otherwise noted, the typical characteristics in the following table applies over the entire recommended power supply voltage range of 1 V to 5.5 V at 25°C with a load of $C_L = 0.1\mu\text{F}$, $R_L = 10\Omega$.

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
TPS22916B, TPS22916BL					
t_{ON}	Turn On Time	$V_{\text{IN}} = 5\text{ V}$		115	μs
		$V_{\text{IN}} = 3.6\text{ V}$		140	
		$V_{\text{IN}} = 1.8\text{ V}$		250	
		$V_{\text{IN}} = 1.2\text{ V}$		350	
		$V_{\text{IN}} = 1\text{ V}$		510	
t_{RISE}	Rise Time	$V_{\text{IN}} = 5\text{ V}$		70	μs
		$V_{\text{IN}} = 3.6\text{ V}$		80	
		$V_{\text{IN}} = 1.8\text{ V}$		130	
		$V_{\text{IN}} = 1.2\text{ V}$		190	
		$V_{\text{IN}} = 1\text{ V}$		240	
SR_{ON}	Slew Rate	$V_{\text{IN}} = 5\text{ V}$		57	$\text{mV}/\mu\text{s}$
		$V_{\text{IN}} = 3.6\text{ V}$		36	
		$V_{\text{IN}} = 1.8\text{ V}$		12	
		$V_{\text{IN}} = 1.2\text{ V}$		5.1	
		$V_{\text{IN}} = 1\text{ V}$		3.3	
t_{OFF}	Turn Off Time	$V_{\text{IN}} = 5\text{ V}$		5	μs
		$V_{\text{IN}} = 3.6\text{ V}$		5	
		$V_{\text{IN}} = 1.8\text{ V}$		10	
		$V_{\text{IN}} = 1.2\text{ V}$		15	
		$V_{\text{IN}} = 1\text{ V}$		25	
t_{FALL}	Fall Time	$C_L = 0.1\mu\text{F}$, $R_L = 10\Omega$ ⁽¹⁾		2.3	μs
		$C_L = 1\mu\text{F}$, $R_L = \text{Open}$ ⁽¹⁾		315	

6.6 Switching Characteristics (continued)

Unless otherwise noted, the typical characteristics in the following table applies over the entire recommended power supply voltage range of 1 V to 5.5 V at 25°C with a load of $C_L = 0.1\mu\text{F}$, $R_L = 10\Omega$.

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
TPS22916C, TPS22916CN, TPS22916CL, TPS22916CNL					
t_{ON}	Turn On Time	$V_{\text{IN}} = 5\text{ V}$		1400	μs
		$V_{\text{IN}} = 3.6\text{ V}$		1700	
		$V_{\text{IN}} = 1.8\text{ V}$		3000	
		$V_{\text{IN}} = 1.2\text{ V}$		5000	
		$V_{\text{IN}} = 1\text{ V}$		6500	
t_{RISE}	Rise Time	$V_{\text{IN}} = 5\text{ V}$		800	μs
		$V_{\text{IN}} = 3.6\text{ V}$		900	
		$V_{\text{IN}} = 1.8\text{ V}$		1400	
		$V_{\text{IN}} = 1.2\text{ V}$		2300	
		$V_{\text{IN}} = 1\text{ V}$		3000	
SR_{ON}	Slew Rate	$V_{\text{IN}} = 5\text{ V}$		5	$\text{mV}/\mu\text{s}$
		$V_{\text{IN}} = 3.6\text{ V}$		3.2	
		$V_{\text{IN}} = 1.8\text{ V}$		1	
		$V_{\text{IN}} = 1.2\text{ V}$		0.4	
		$V_{\text{IN}} = 1\text{ V}$		0.3	
t_{OFF}	Turn Off Time	$V_{\text{IN}} = 5\text{ V}$		5	μs
		$V_{\text{IN}} = 3.6\text{ V}$		5	
		$V_{\text{IN}} = 1.8\text{ V}$		10	
		$V_{\text{IN}} = 1.2\text{ V}$		15	
		$V_{\text{IN}} = 1\text{ V}$		25	
t_{FALL}	Fall Time ⁽²⁾	$C_L = 0.1\mu\text{F}$, $R_L = 10\Omega$ ⁽¹⁾		2.3	μs
		$C_L = 10\mu\text{F}$, $R_L = \text{Open}$ ⁽¹⁾		3150	

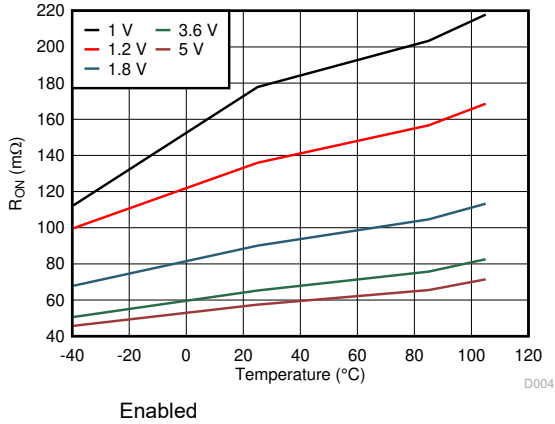
(1) See the [Fall Time \(\$t_{\text{FALL}}\$ \) and Quick Output Discharge \(QOD\)](#) section for information on how R_L and C_L affect Fall Time.

(2) Devices without Quick Output Discharge (QOD) may not discharge completely.

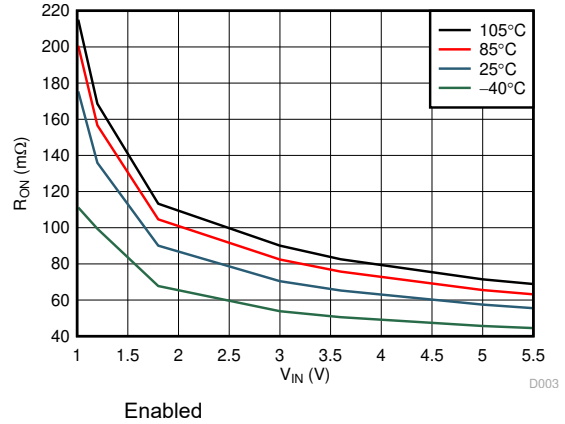
6.7 Typical Characteristics

6.7.1 Typical Electrical Characteristics

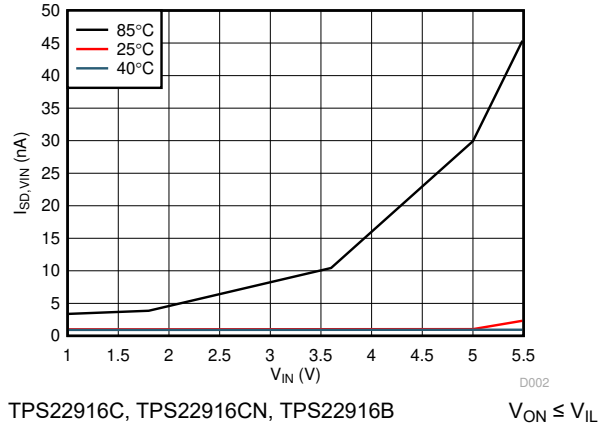
The typical characteristics curves in this section apply to all devices unless otherwise noted.



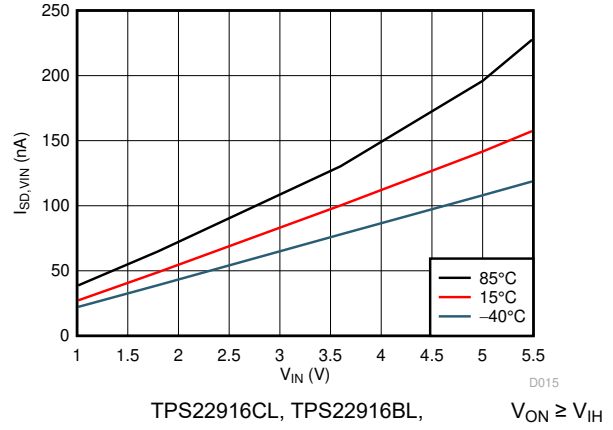
Enabled
Figure 6-1. ON-Resistance vs Temperature



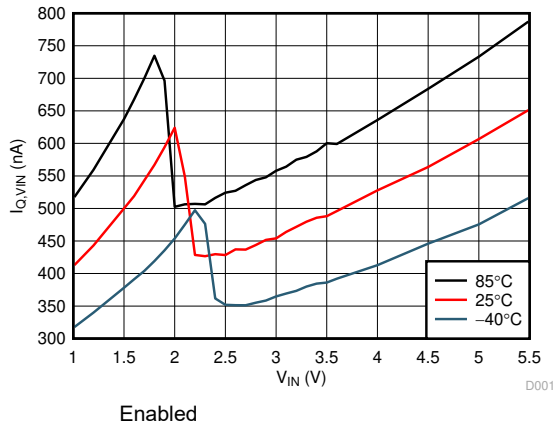
Enabled
Figure 6-2. ON-Resistance vs Input voltage



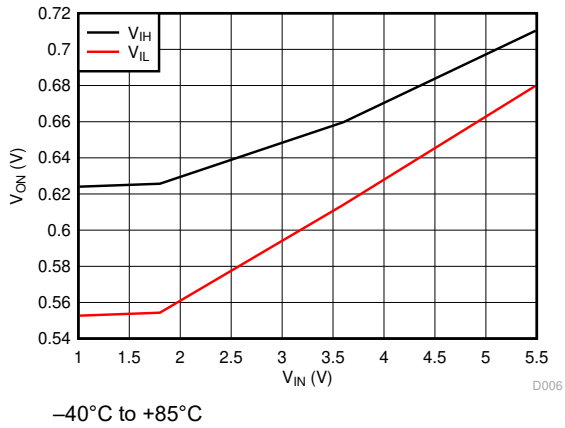
TPS22916C, TPS22916CN, TPS22916B
 $V_{ON} \leq V_{IL}$
Figure 6-3. Shutdown Current



TPS22916CL, TPS22916BL, TPS22916CNL
 $V_{ON} \geq V_{IH}$
Figure 6-4. Shutdown Current (Active Low)



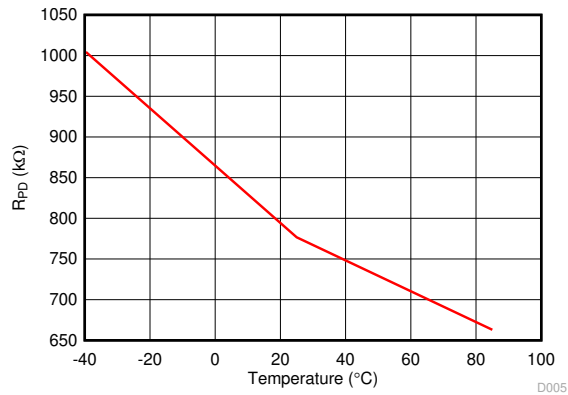
Enabled
Figure 6-5. Quiescent Current



-40°C to $+85^{\circ}\text{C}$
Figure 6-6. ON Pin Threshold

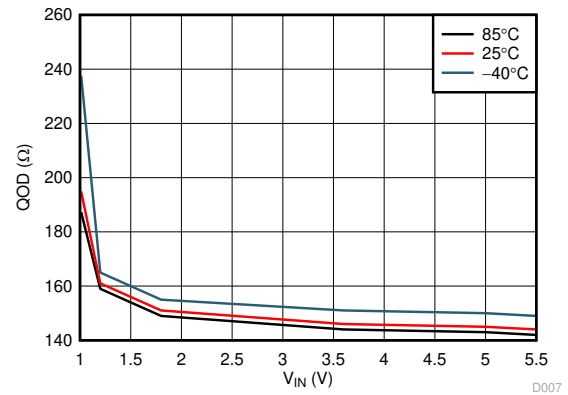
6.7.1 Typical Electrical Characteristics (continued)

The typical characteristics curves in this section apply to all devices unless otherwise noted.



$V_{ON} \leq V_{IL}$

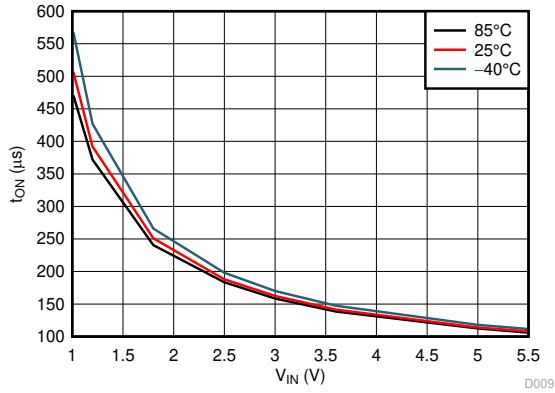
Figure 6-7. ON Pin Smart Pulldown



TPS22916C, TPS22916CL, TPS22916B, TPS22916BL

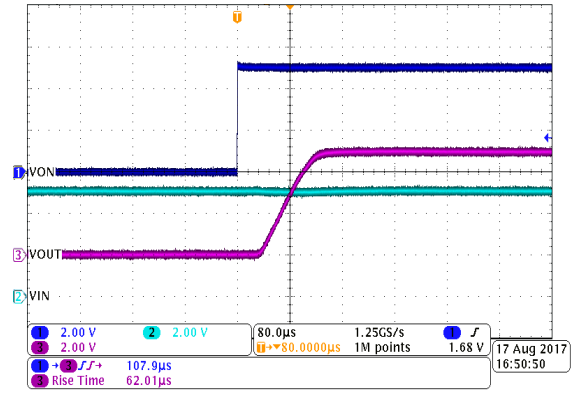
Figure 6-8. Quick Output Discharge

6.7.2 Typical Switching Characteristics



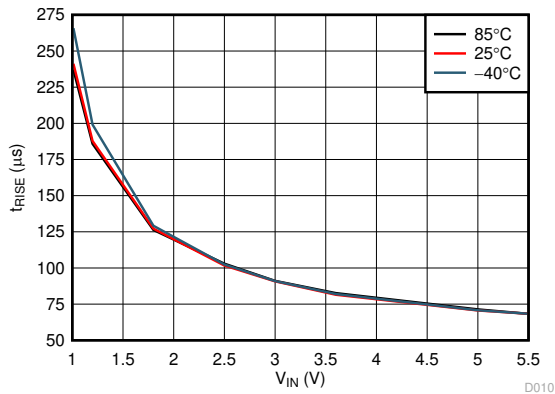
C_L = 0.1 µF R_L = 10 Ω

Figure 6-9. Fast Turn-On Time



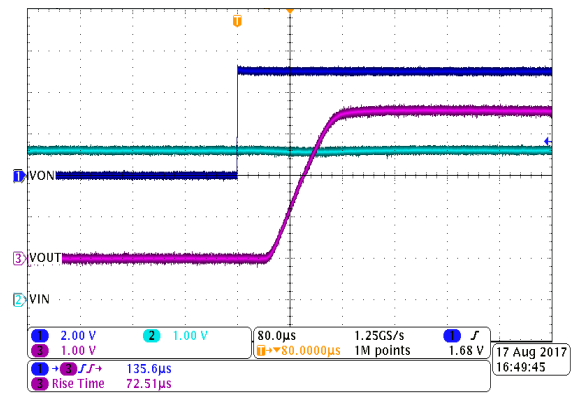
TPS22916B V_{IN} = 5 V C_L = 0.1 µF R_L = 10 Ω

Figure 6-10. Fast Turn-On at 5 V



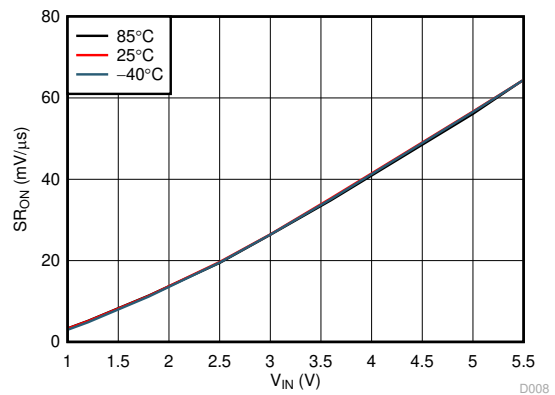
C_L = 0.1 µF R_L = 10 Ω

Figure 6-11. Fast Rise Time



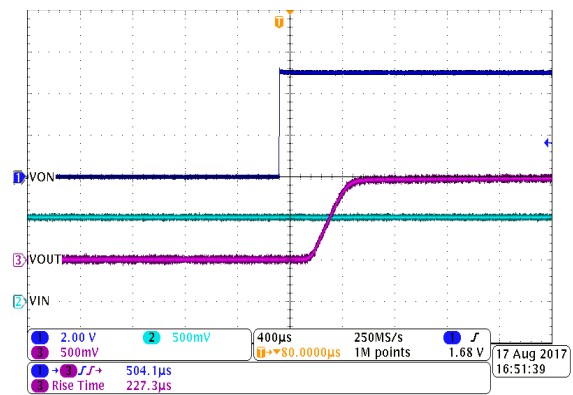
TPS22916B V_{IN} = 3.6 V C_L = 0.1 µF R_L = 10 Ω

Figure 6-12. Fast Turn-On at 3.6 V



C_L = 0.1 µF R_L = 10 Ω

Figure 6-13. Fast Slew Rate



TPS22916B V_{IN} = 1 V C_L = 0.1 µF R_L = 10 Ω

Figure 6-14. Fast Turn-On at 1 V

6.7.2 Typical Switching Characteristics (continued)

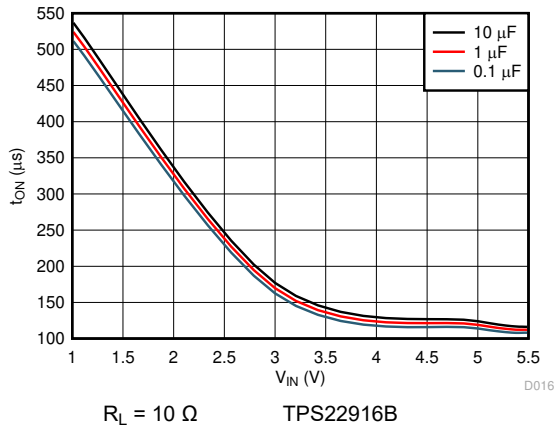


Figure 6-15. Fast Turn-On vs Load Capacitance

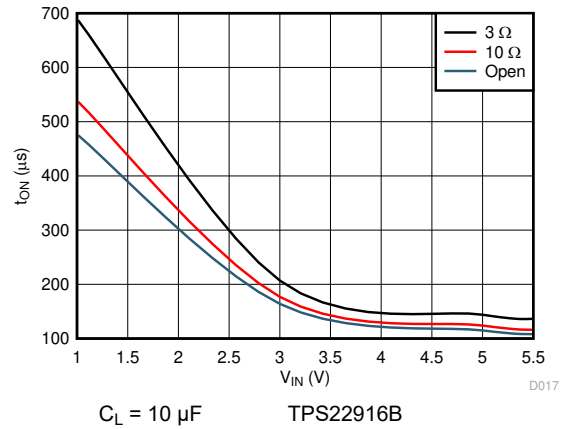


Figure 6-16. Fast Turn-On vs Load Resistance

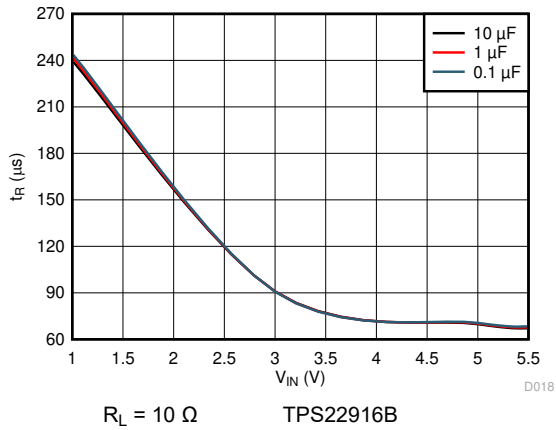


Figure 6-17. Fast Rise Time vs Load Capacitance

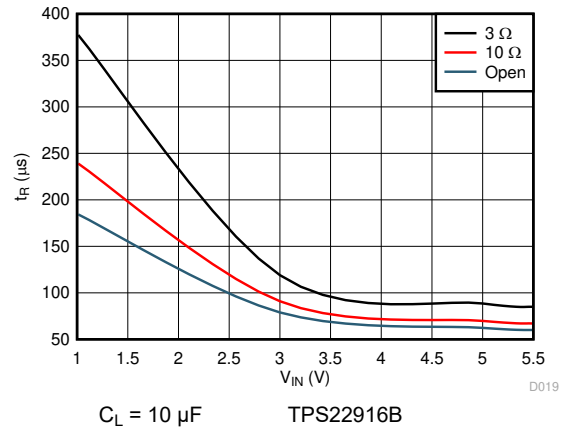


Figure 6-18. Fast Rise Time vs Load Resistance

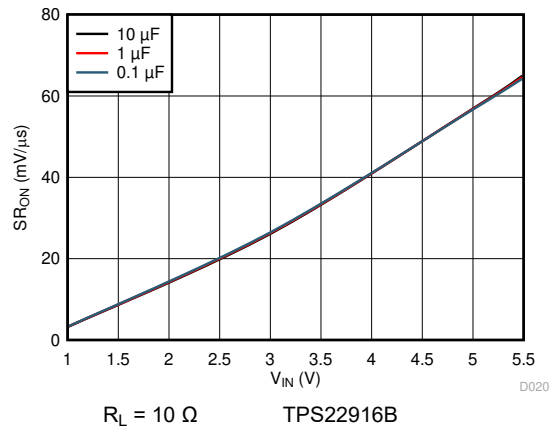


Figure 6-19. Fast Slew Rate vs Load Capacitance

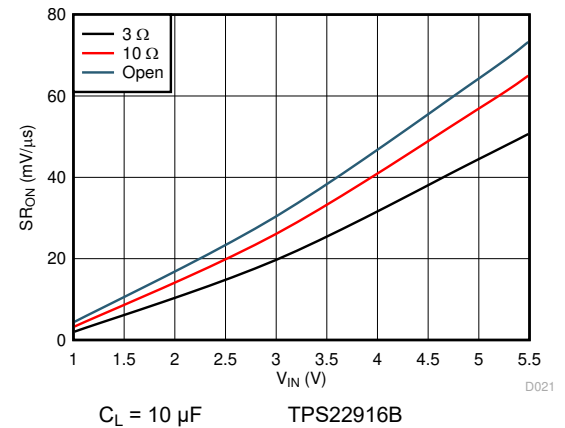
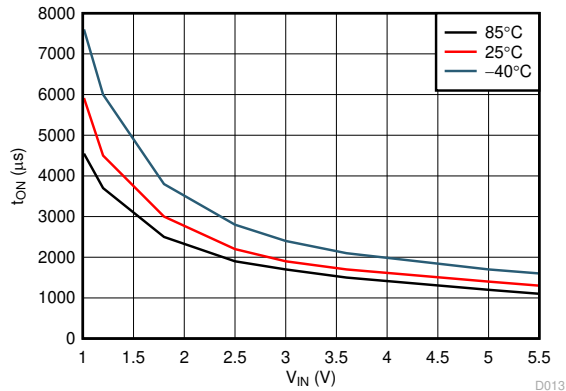


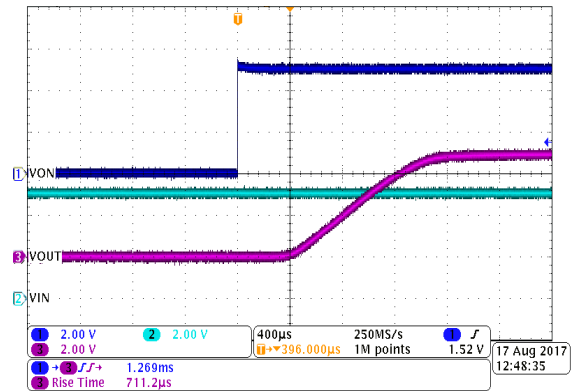
Figure 6-20. Fast Slew Rate vs Load Resistance

6.7.2 Typical Switching Characteristics (continued)



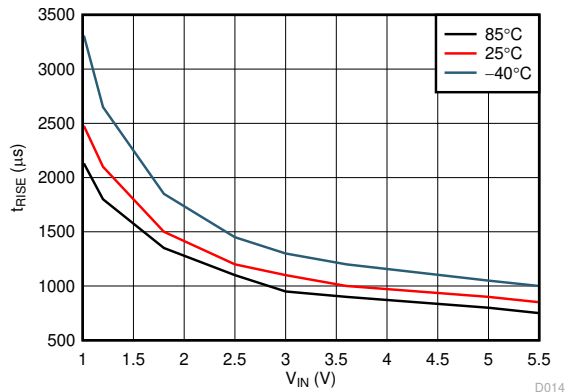
$C_L = 0.1 \mu\text{F}$ $R_L = 10 \Omega$

Figure 6-21. Slow Turn-On Time



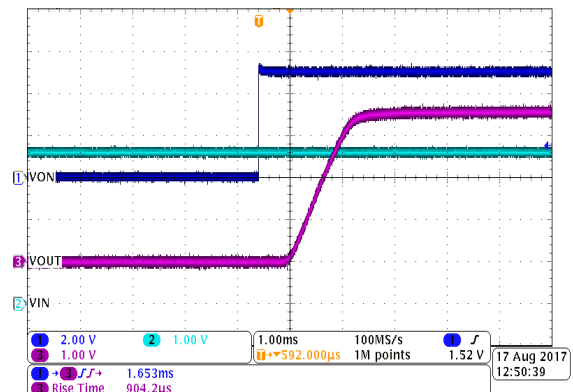
TPS22916C $V_{IN} = 5 \text{ V}$ $C_L = 0.1 \mu\text{F}$ $R_L = 10 \Omega$

Figure 6-22. Slow Turn-On at 5 V



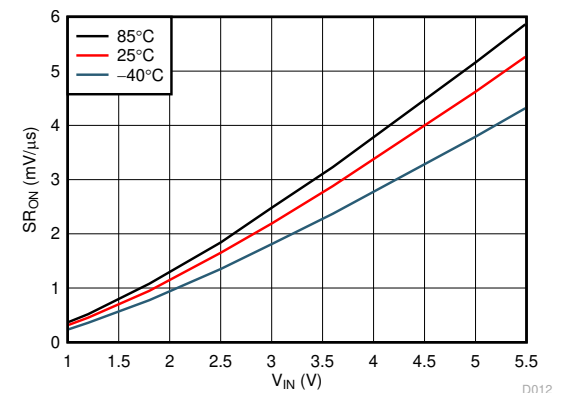
$C_L = 0.1 \mu\text{F}$ $R_L = 10 \Omega$

Figure 6-23. Slow Rise Time



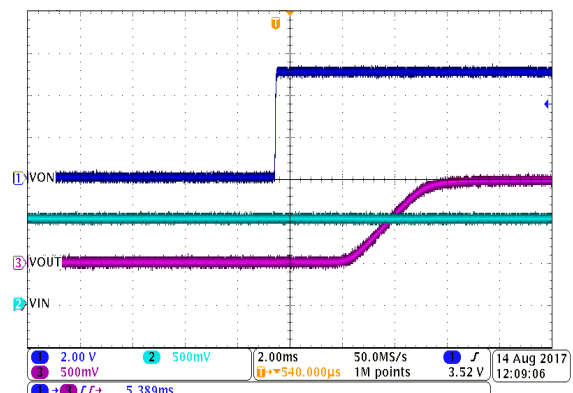
TPS22916C $V_{IN} = 3.6 \text{ V}$ $C_L = 0.1 \mu\text{F}$ $R_L = 10 \Omega$

Figure 6-24. Slow Turn-On at 3.6 V



$C_L = 0.1 \mu\text{F}$ $R_L = 10 \Omega$

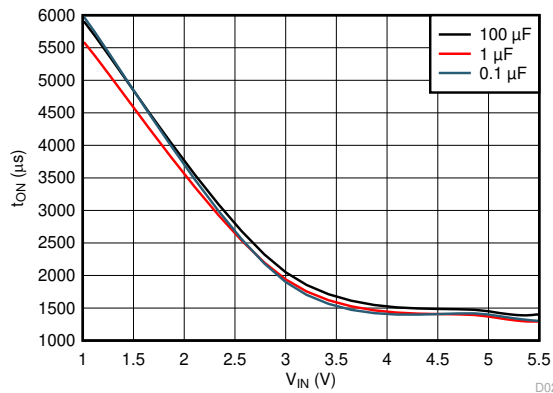
Figure 6-25. Slow Slew Rate



TPS22916C $V_{IN} = 1 \text{ V}$ $C_L = 0.1 \mu\text{F}$ $R_L = 10 \Omega$

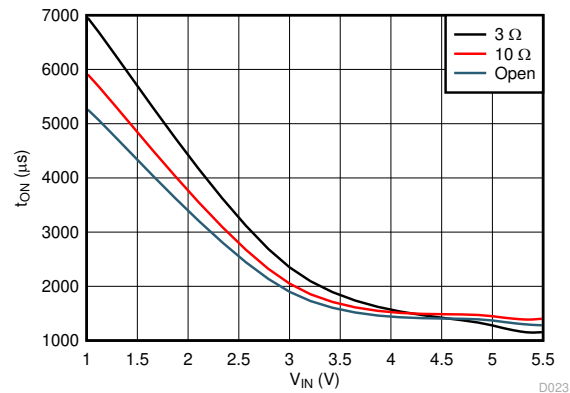
Figure 6-26. Slow Turn-On at 1 V

6.7.2 Typical Switching Characteristics (continued)



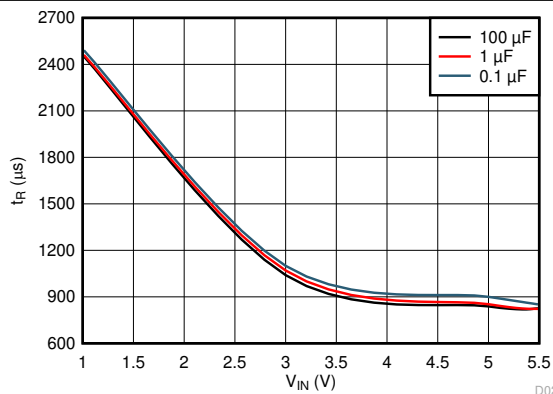
$R_L = 10 \Omega$ TPS22916C TPS22916CN TPS22916CL

Figure 6-27. Slow Turn-On vs Load Capacitance



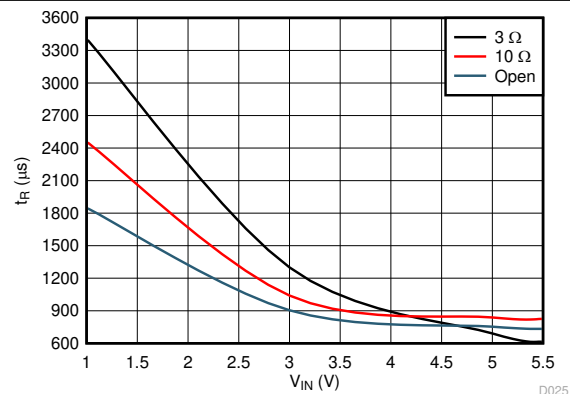
$C_L = 100 \mu F$ TPS22916C TPS22916CN TPS22916CL

Figure 6-28. Slow Turn-On vs Load Resistance



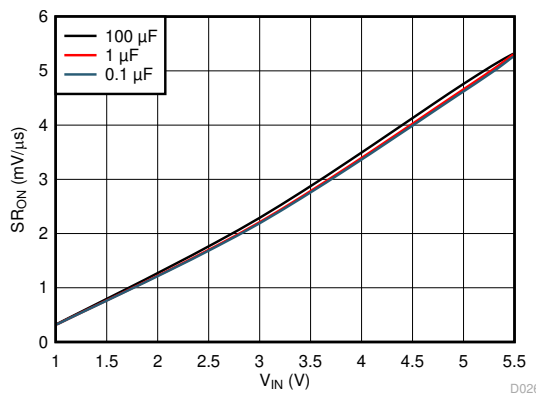
$R_L = 10 \Omega$ TPS22916C TPS22916CN TPS22916CL

Figure 6-29. Slow Rise Time vs Load Capacitance



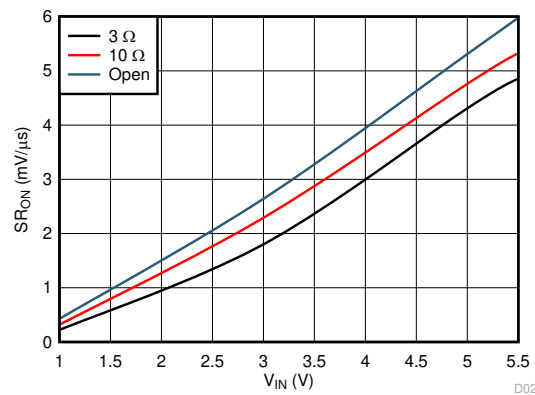
$C_L = 100 \mu F$ TPS22916C TPS22916CN TPS22916CL

Figure 6-30. Slow Rise Time vs Load Resistance



$R_L = 10 \Omega$ TPS22916C TPS22916CN TPS22916CL

Figure 6-31. Slow Slew Rate vs Load Capacitance



$C_L = 100 \mu F$ TPS22916C TPS22916CN TPS22916CL

Figure 6-32. Slow Slew Rate vs Load Resistance

6.7.2 Typical Switching Characteristics (continued)

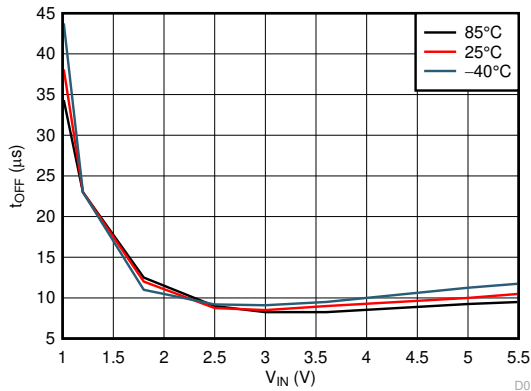
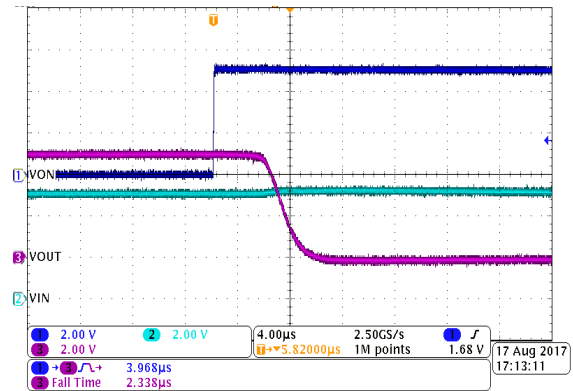
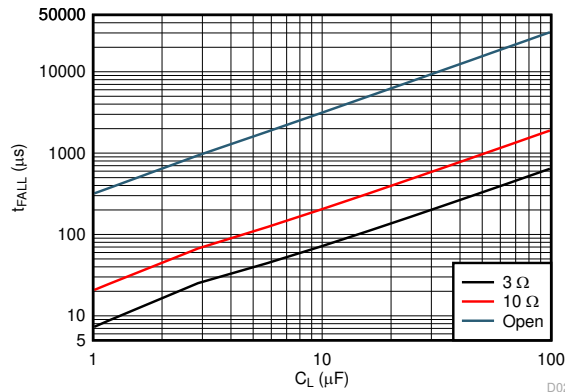


Figure 6-33. Turn-Off Time



TPS22916CL V_{IN} = 5 V C_L = 0.1 μF R_L = 10 Ω

Figure 6-34. Turn-Off at 5 V (Active Low)



V_{IN} = 1 V to 5.5 V TPS22916C TPS22916CL TPS22916B

Figure 6-35. Fall Time

7 Parameter Measurement Information

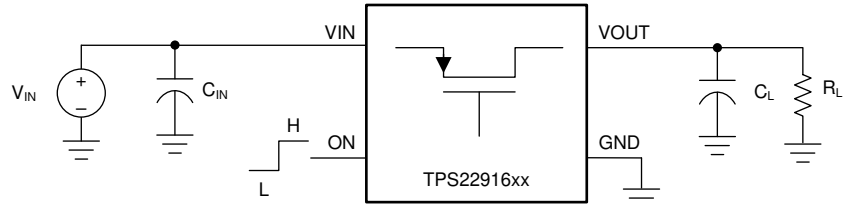
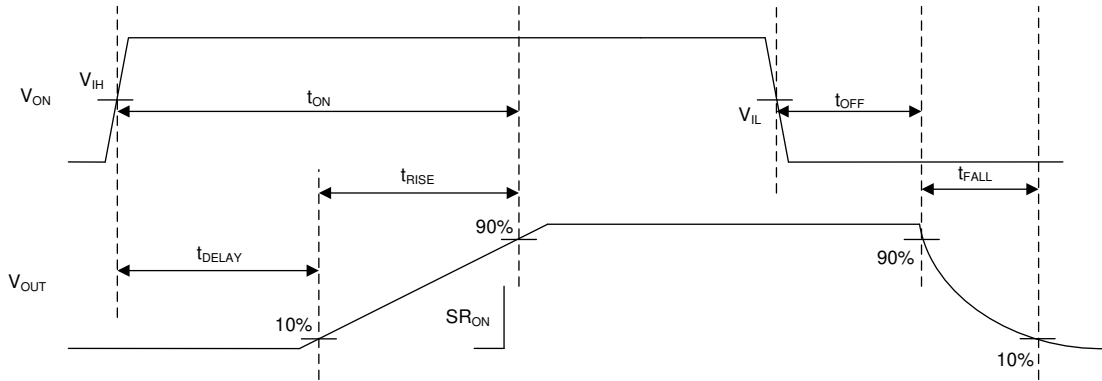


Figure 7-1. TPS22916 Test Circuit



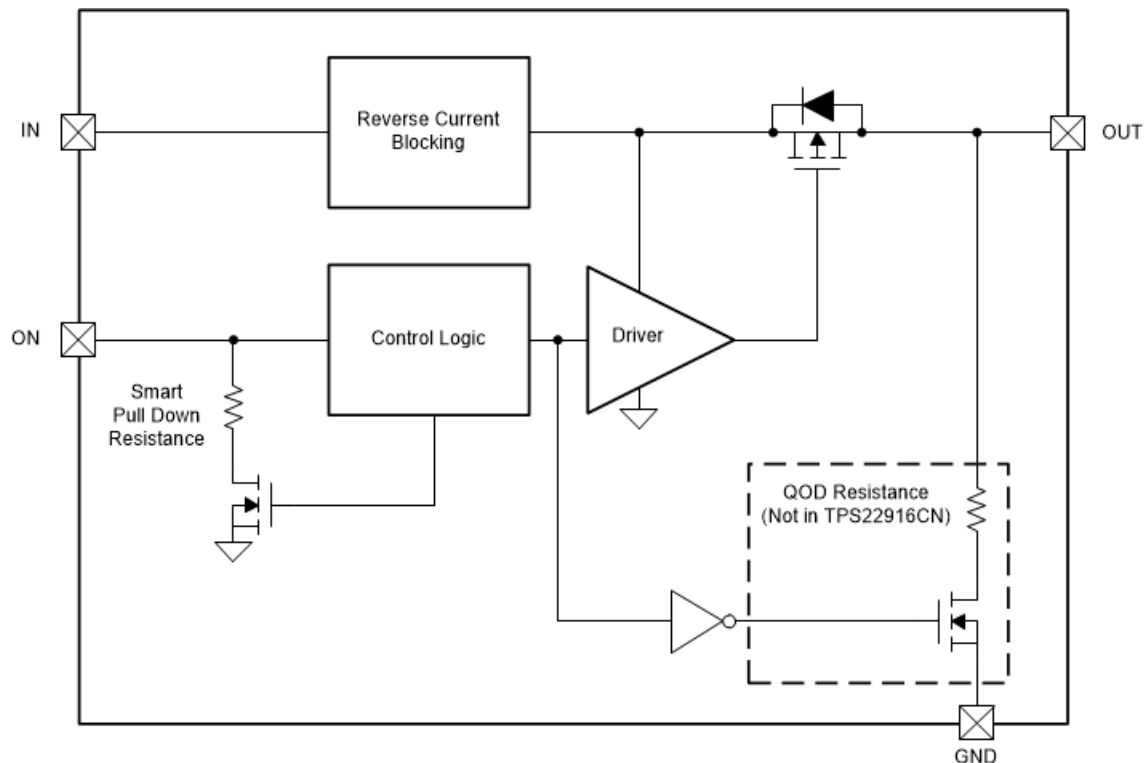
8 Detailed Description

8.1 Overview

This family of devices are single channel, 2-A load switches in ultra-small, space saving 4-pin WCSP package. These devices implement a low resistance P-channel MOSFET with a controlled rise time for applications that must limit inrush current.

These devices are designed to have very low leakage current during OFF state. This design prevents downstream circuits from pulling high standby current from the supply. Integrated control logic, driver, power supply, and output discharge FET eliminates the need for additional external components, which reduces solution size and BOM count.

8.2 Functional Block Diagram



8.3 Feature Description

8.3.1 On and Off Control

The ON pin controls the state of the switch. The ON pin is compatible with standard GPIO logic threshold. the pin can be used with any microcontroller with 1.2-V, 1.8-V, 2.5-V, 3.3-V, or 5.5-V GPIO.

8.3.2 Fall Time (t_{FALL}) and Quick Output Discharge (QOD)

The TPS22916B, TPS22916BL, TPS22916C, and TPS22916CL include a Quick Output Discharge feature. When the switch is disabled, a discharge resistor is connected between VOUT and GND. This resistor has a typical value of QOD and prevents the output from floating while the switch is disabled.

As load capacitance and load resistance increase: t_{FALL} increases. The larger the load resistance or load capacitance is, the longer it takes to discharge the capacitor, resulting in a longer fall time.

The output fall time is determined by how quickly the load capacitance is discharged and can be found using Equation 1 .

$$t_{\text{FALL}} = - (R_{\text{DIS}}) \times C_{\text{L}} \times \ln (V_{10\%} / V_{90\%}) \quad (1)$$

Where

- $V_{10\%}$ is 10% of the initial output voltage
- $V_{90\%}$ is 90% of the initial output voltage
- R_{DIS} is the result of the QOD resistance in parallel with the Load Resistance R_{L}
- C_{L} is the load capacitance

With the Quick Output Discharge feature, the QOD resistance is in parallel with R_{L} . This provides a lower total load resistance as seen from the load capacitance which discharges the capacitance faster resulting in a smaller t_{FALL} .

8.3.3 Full-Time Reverse Current Blocking

In a scenario where the device is enabled and V_{OUT} is greater than V_{IN} there is potential for reverse current to flow through the pass FET or the body diode. When the reverse current threshold (I_{RCB}) is exceeded, the switch is disabled within t_{RCB} . The switch remains off and block reverse current as long as the reverse voltage condition exists. After V_{OUT} has dropped below the V_{RCB} release threshold the TPS22916xx turns back on with slew rate control.

8.4 Device Functional Modes

Table 8-1 describes the state for each variant as determined by the ON pin.

Table 8-1. Device Function Table

ON	TPS22916B	TPS22916BL	TPS22916C	TPS22916CN	TPS22916CL	TPS22916CNL
$\leq V_{\text{IL}}$	Disabled	Enabled	Disabled	Disabled	Enabled	Enabled
$\geq V_{\text{IH}}$	Enabled	Disabled	Enabled	Enabled	Disabled	Disabled

Table 8-2 shows when QOD is active for each variant.

Table 8-2. QOD Function Table

Device	TPS22916B	TPS22916BL	TPS22916C	TPS22916CN	TPS22916CL	TPS22916CNL
Enabled	No	No	No	No	No	No
Disabled	Yes	Yes	Yes	No	Yes	No

Table 8-3 shows when the ON pin smart pulldown is active.

Table 8-3. Smart-ON Pulldown

V_{ON}	Pulldown
$\leq V_{\text{IL}}$	Connected
$\geq V_{\text{IH}}$	Disconnected

9 Application and Implementation

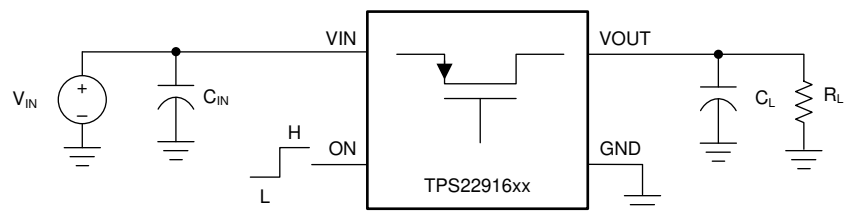
Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

9.1 Application Information

This section highlights some of the design considerations when implementing this device in various applications. A PSPICE model for this device is also available in the product page of this device.

9.2 Typical Application



Copyright © 2017, Texas Instruments Incorporated

Figure 9-1. Typical Application

9.2.1 Design Requirements

For this design example, below, use the input parameters shown in Table 9-1.

Table 9-1. Design Parameters

Design Parameter	Example Value
Input voltage (V_{IN})	3.6 V
Load capacitance (C_L)	47 μ F
Maximum inrush current (I_{RUSH})	300 mA

9.2.2 Detailed Design Procedure

9.2.2.1 Maximum Inrush Current

When the switch is enabled, the output capacitors must be charged up from 0 V to V_{IN} voltage. This charge arrives in the form of inrush current. Inrush current can be calculated using the following equation:

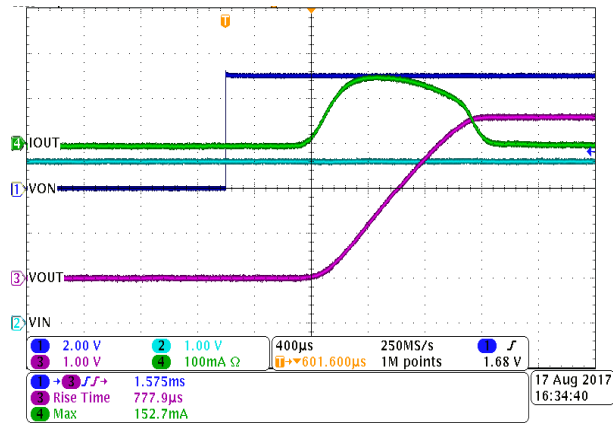
$$I_{RUSH} = C_L \times SR_{ON} \tag{2}$$

$$I_{RUSH} = 47 \mu\text{F} \times 3.2 \text{ mV}/\mu\text{s} \tag{3}$$

$$I_{RUSH} = 150 \text{ mA} \tag{4}$$

The TPS22916x offers multiple rise time options to control the inrush current during turn-on. The appropriate device can be selected based upon the maximum acceptable slew rate which can be calculated using the design requirements and the inrush current equation. In this case, the TPS22916C provides a slew rate slow enough to limit the inrush current to the desired amount.

9.2.3 Application Curve



V_{IN} = 3.6 V C_L = 47 µF R_L = Open
 TPS22916C T_A = 25°C

Figure 9-2. Inrush Current

10 Power Supply Recommendations

The device is designed to operate with a V_{IN} range of 1 V to 5.5 V. The V_{IN} power supply must be well regulated and placed as close to the device terminal as possible. The power supply must be able to withstand all transient load current steps. In most situations, using an input capacitance (C_{IN}) of 1 µF is sufficient to prevent the supply voltage from dipping when the switch is turned on. In cases where the power supply is slow to respond to a large transient current or large load current step, additional bulk capacitance can be required on the input.

11 Layout

11.1 Layout Guidelines

For best performance, all traces must be as short as possible. To be most effective, the input and output capacitors must be placed close to the device to minimize the effects that parasitic trace inductances can have on normal operation. Using wide traces for VIN, VOUT, and GND helps minimize the parasitic electrical effects.

11.2 Layout Example

Equation 3 shows an example for these devices. Notice the connection to system ground between the V_{OUT} Bypass Capacitor ground and the GND pin of the load switch,. This connection creates a ground barrier which helps to reduce the ground noise seen by the device.

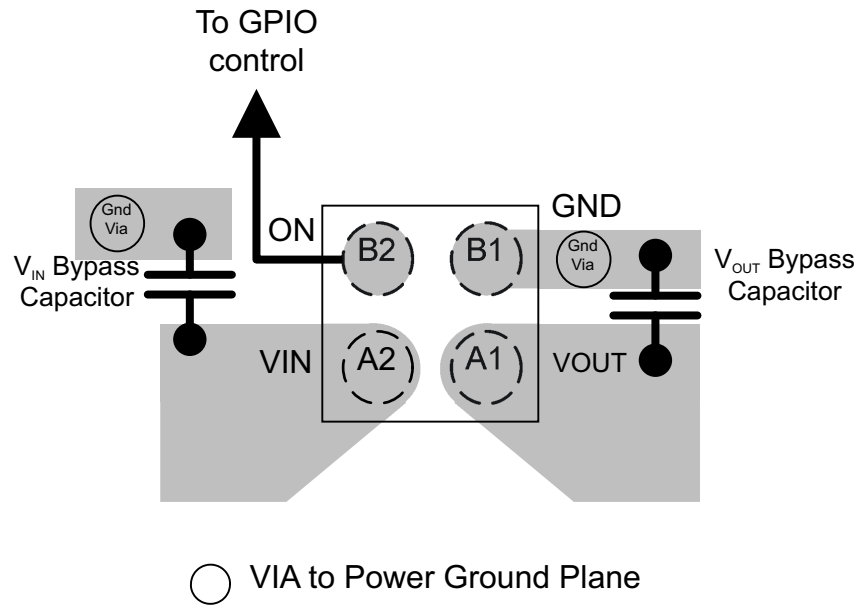


Figure 11-1. TPS22916xx Layout

11.3 Thermal Considerations

The maximum IC junction temperature must be restricted to 125°C under normal operating conditions. To calculate the maximum allowable dissipation, $P_{D(max)}$ for a given output current and ambient temperature, use Equation 5 as a guideline:

$$P_{D(MAX)} = \frac{T_{J(MAX)} - T_A}{R_{\theta JA}} \quad (5)$$

Where,

$P_{D(max)}$ = maximum allowable power dissipation

$T_{J(max)}$ = maximum allowable junction temperature

T_A = ambient temperature for the device

θ_{JA} = junction to air thermal impedance. See the [Thermal Information](#) section.

12 Device and Documentation Support

12.1 Documentation Support

12.1.1 Related Documentation

For related documentation see the following:

Texas Instruments, [TPS22916 Load Switch Evaluation Module User's Guide](#)

12.2 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on [ti.com](#). Click on *Subscribe to updates* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

12.3 Support Resources

[TI E2E™ support forums](#) are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

Linked content is provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's [Terms of Use](#).

12.4 Trademarks

TI E2E™ is a trademark of Texas Instruments.

All trademarks are the property of their respective owners.

12.5 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

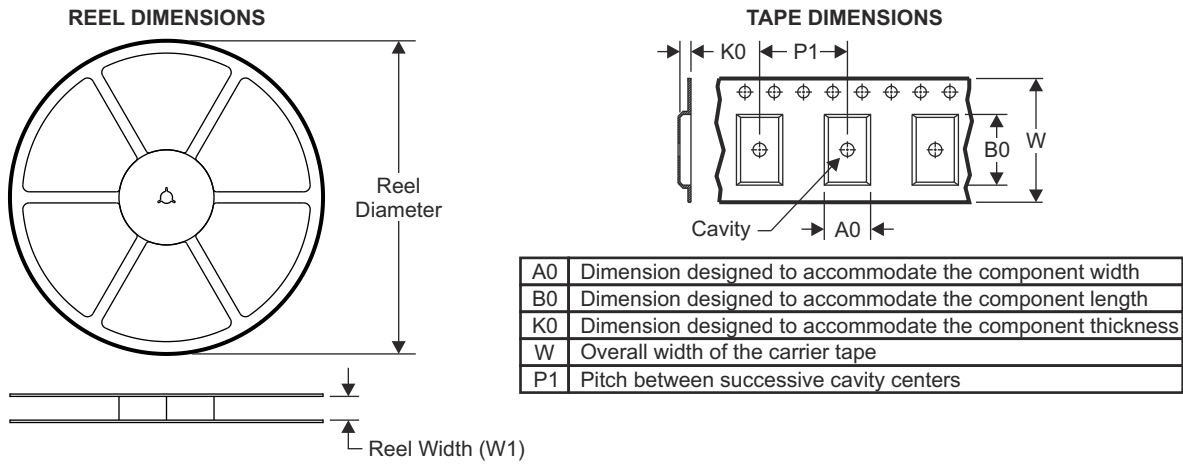
12.6 Glossary

[TI Glossary](#) This glossary lists and explains terms, acronyms, and definitions.

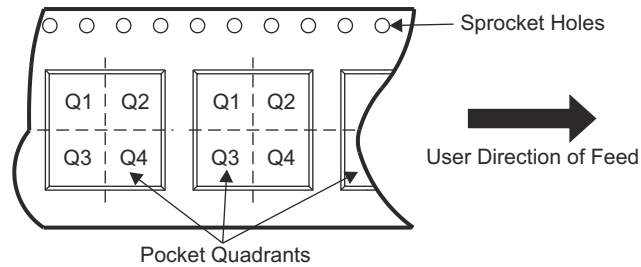
13 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

13.1 Tape and Reel Information

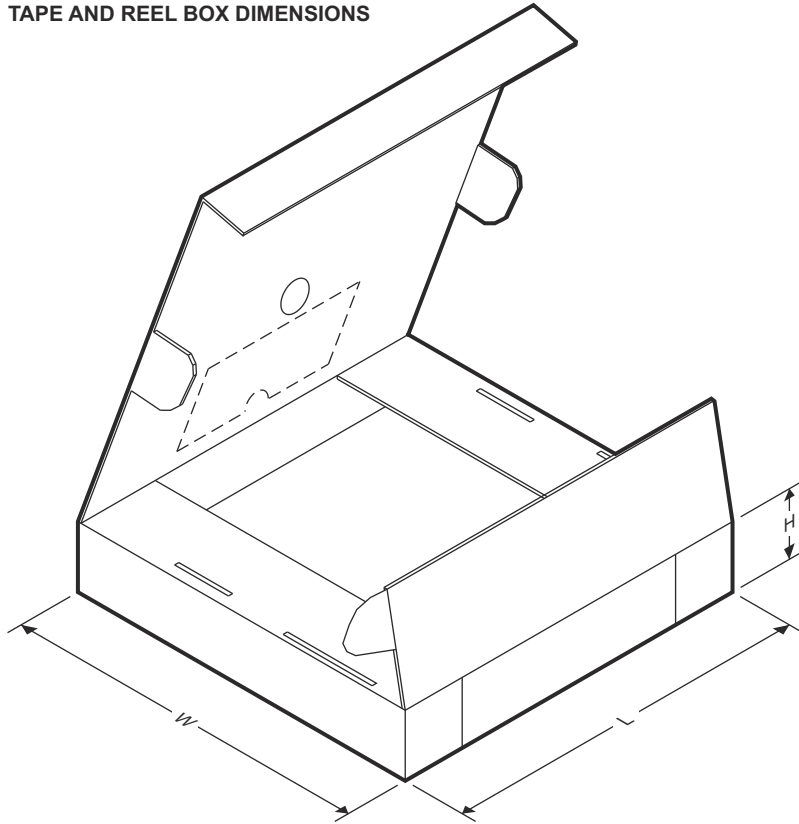


QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TPS22916BYFPR	DSBGA	YFP	4	3000	180.0	8.4	0.86	0.86	0.59	4.0	8.0	Q1
TPS22916BYFPT	DSBGA	YFP	4	250	180.0	8.4	0.86	0.86	0.59	4.0	8.0	Q1
TPS22916CLYFPR	DSBGA	YFP	4	3000	180.0	8.4	0.86	0.86	0.59	4.0	8.0	Q1
TPS22916CLYFPT	DSBGA	YFP	4	250	180.0	8.4	0.86	0.86	0.59	4.0	8.0	Q1
TPS22916CNYFPR	DSBGA	YFP	4	3000	180.0	8.4	0.86	0.86	0.59	4.0	8.0	Q1
TPS22916CNYFPT	DSBGA	YFP	4	250	180.0	8.4	0.86	0.86	0.59	4.0	8.0	Q1
TPS22916CYFPR	DSBGA	YFP	4	3000	180.0	8.4	0.86	0.86	0.59	4.0	8.0	Q1
TPS22916CYFPT	DSBGA	YFP	4	250	180.0	8.4	0.86	0.86	0.59	4.0	8.0	Q1
TPS22916CNLYFPR	DSBGA	YFP	4	3000	180.0	8.4	0.86	0.86	0.59	4.0	8.0	Q1
TPS22916BLYFPR	DSBGA	YFP	4	3000	180.0	8.4	0.86	0.86	0.59	4.0	8.0	Q1

TAPE AND REEL BOX DIMENSIONS



Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TPS22916BYFPR	DSBGA	YFP	4	3000	182.0	182.0	20.0
TPS22916BYFPT	DSBGA	YFP	4	250	182.0	182.0	20.0
TPS22916CLYFPR	DSBGA	YFP	4	3000	182.0	182.0	20.0
TPS22916CLYFPT	DSBGA	YFP	4	250	182.0	182.0	20.0
TPS22916CNYFPR	DSBGA	YFP	4	3000	182.0	182.0	20.0
TPS22916CNYFPT	DSBGA	YFP	4	250	182.0	182.0	20.0
TPS22916CYFPR	DSBGA	YFP	4	3000	182.0	182.0	20.0
TPS22916CYFPT	DSBGA	YFP	4	250	182.0	182.0	20.0
TPS22916CNLYFPR	DSBGA	YFP	4	3000	182.0	182.0	20.0
TPS22916BLYFPR	DSBGA	YFP	4	3000	182.0	182.0	20.0

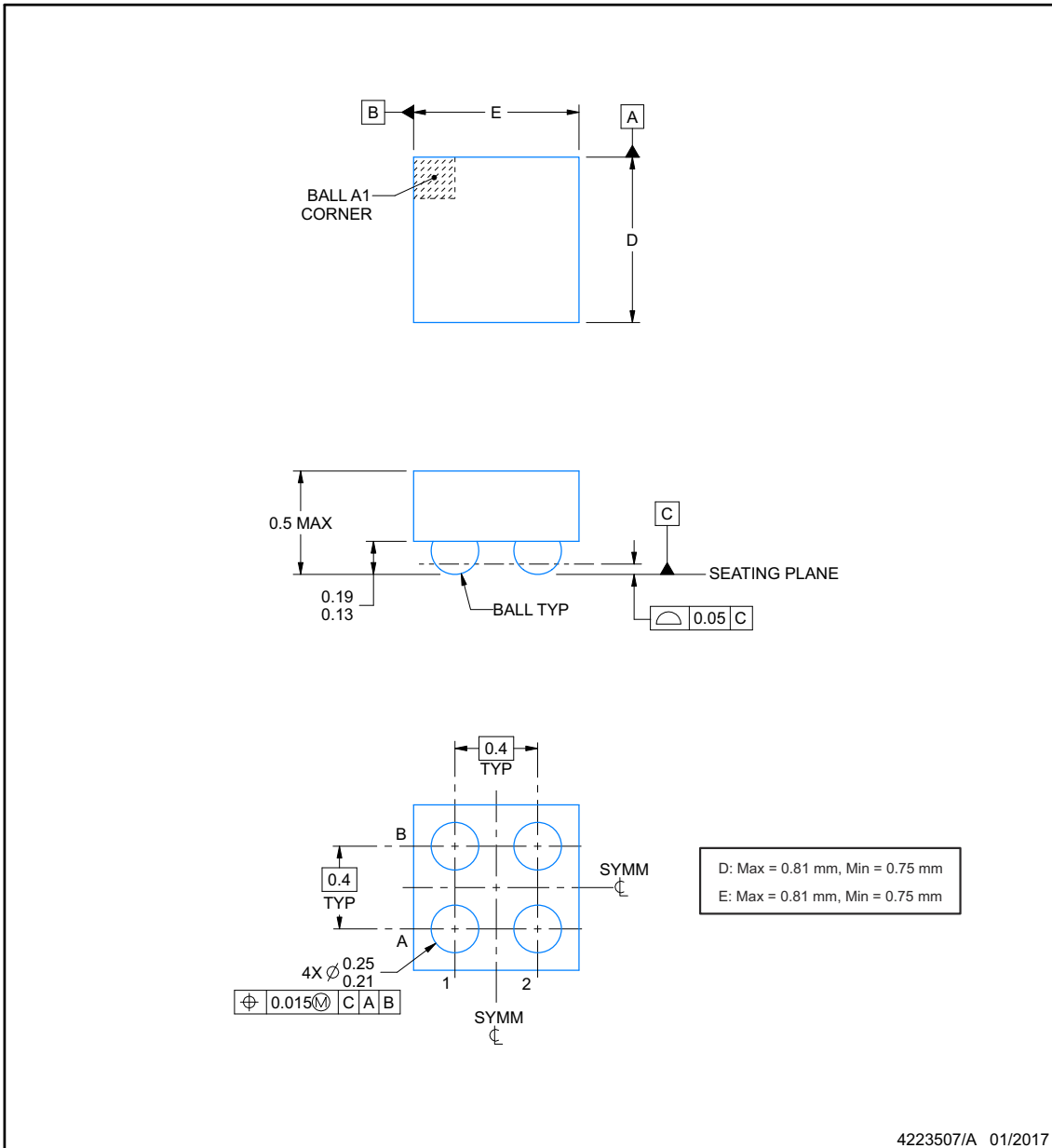


PACKAGE OUTLINE

YFP0004

DSBGA - 0.5 mm max height

DIE SIZE BALL GRID ARRAY



NOTES:

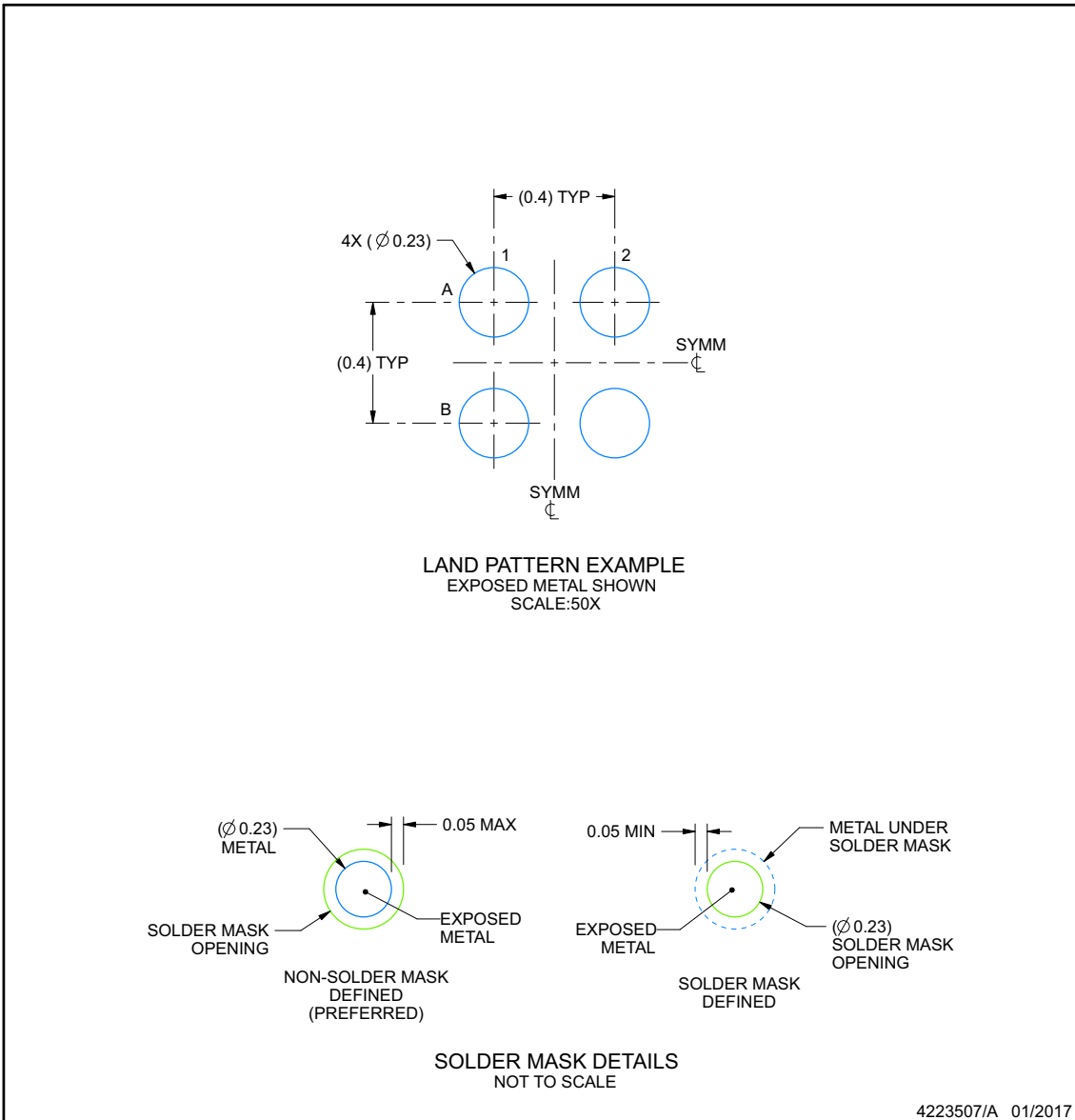
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.

EXAMPLE BOARD LAYOUT

YFP0004

DSBGA - 0.5 mm max height

DIE SIZE BALL GRID ARRAY



NOTES: (continued)

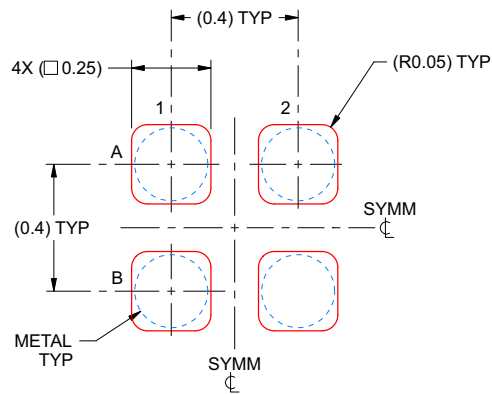
- Final dimensions may vary due to manufacturing tolerance considerations and also routing constraints. For more information, see Texas Instruments literature number SNVA009 (www.ti.com/lit/snva009).

EXAMPLE STENCIL DESIGN

YFP0004

DSBGA - 0.5 mm max height

DIE SIZE BALL GRID ARRAY



SOLDER PASTE EXAMPLE
BASED ON 0.1 mm THICK STENCIL
SCALE:50X

4223507/A 01/2017

NOTES: (continued)

4. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release.

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
TPS22916BLYFPR	ACTIVE	DSBGA	YFP	4	3000	RoHS & Green	SNAGCU	Level-1-260C-UNLIM	-40 to 85	Q	Samples
TPS22916BYFPR	ACTIVE	DSBGA	YFP	4	3000	RoHS & Green	SAC396 SNAGCU	Level-1-260C-UNLIM	-40 to 85	(BA, R)	Samples
TPS22916BYFPT	ACTIVE	DSBGA	YFP	4	250	RoHS & Green	SAC396 SNAGCU	Level-1-260C-UNLIM	-40 to 85	(BA, R)	Samples
TPS22916CLYFPR	ACTIVE	DSBGA	YFP	4	3000	RoHS & Green	SAC396	Level-1-260C-UNLIM	-40 to 85	B9	Samples
TPS22916CLYFPT	ACTIVE	DSBGA	YFP	4	250	RoHS & Green	SAC396	Level-1-260C-UNLIM	-40 to 85	B9	Samples
TPS22916CNLYFPR	ACTIVE	DSBGA	YFP	4	3000	RoHS & Green	SNAGCU	Level-1-260C-UNLIM	-40 to 85	S	Samples
TPS22916CNYFPR	ACTIVE	DSBGA	YFP	4	3000	RoHS & Green	SAC396	Level-1-260C-UNLIM	-40 to 85	B8	Samples
TPS22916CNYFPT	ACTIVE	DSBGA	YFP	4	250	RoHS & Green	SAC396	Level-1-260C-UNLIM	-40 to 85	B8	Samples
TPS22916CYFPR	ACTIVE	DSBGA	YFP	4	3000	RoHS & Green	SAC396	Level-1-260C-UNLIM	-40 to 85	B7	Samples
TPS22916CYFPT	ACTIVE	DSBGA	YFP	4	250	RoHS & Green	SAC396	Level-1-260C-UNLIM	-40 to 85	B7	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.